

HMC802ALP3E

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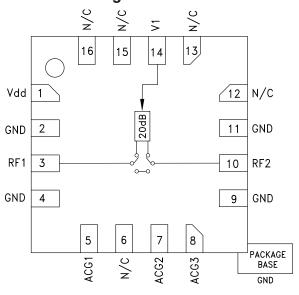
20 dB GaAs MMIC 1-BIT DIGITAL POSITIVE CONTROL ATTENUATOR, DC - 10 GHz

Typical Applications

The HMC802ALP3E is ideal for both RF and IF applications:

- Test Equipment and Sensors
- ISM, MMDS, WLAN, WiMAX, WiBro
- Microwave Radio & VSAT
- Cellular Infrastructure

Functional Diagram



Features

± 0.6 dB Typical Step Error Low Insertion Loss: 3 dB

High IP3: +55 dBm Single Control Line

TTL/CMOS Compatible Control

Single +5V Supply

16 Lead 3x3mm SMT Package: 9mm²

General Description

The HMC802ALP3E is a broadband bidirectional 1-bit GaAs IC digital attenuator in a low cost leadless surface mount package. This single positive control line digital attenuator utilizes off chip AC ground capacitors for near DC operation, making it suitable for a wide variety of RF and IF applications. Covering DC to 10 GHz, the insertion loss is less than 3 dB typical and attenuation accuracy is excellent at ±0.6 dB typical. The attenuator also features a high IIP3 of +55 dBm. One TTL/CMOS control input is used to select the attenuation state and a single Vdd bias of +5V is required.

Electrical Specifications, $T_A = +25^{\circ}$ C, With Vdd = +5V & VctI = 0/+5V

| Parameter | Frequency (GHz) | Min. | Тур. | Max. | Units |
|---|---------------------------------------|----------------------|-------------------------------------|----------------------|----------------|
| Insertion Loss | DC - 4 GHz 4 - 8 GHz 8 - 10 GHz | | 0.9 1.5 2.5 | 1.7 2.8 3.5 | dB dB dB |
| Attenuation Range | DC - 10 GHz | | 20 | | dB |
| Return Loss (RF1 & RF2, Both States) | DC - 6 GHz 6 - 10 GHz | | 25 15 | | dB dB |
| Attenuation Accuracy: (Referenced to Insertion Loss) ¹ | DC - 6 GHz 6 - 8 GHz 8 - 10 GHz | -1.0 -2.0 -2.6 | -0.6/+0.5 -1.6/+0.5 -2.3/+0.8 | +0.6 +0.6 +1.2 | dB dB |
| Input Power for 0.1 dB Compression | DC - 10 GHz | | 27 | | dBm |
| Input Third Order Intercept Point (Two-Tone Input Power= 14 dBm Each Tone) | DC - 10 GHz | | 55 | | dBm |
| Switching Characteristics | | | | | |
| tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF) | DC - 10 GHz | | 70 90 | | ns ns |
| 1. STEP SIZE IS 20DB FOR ALL FREQUENCY | | • | | | • |

HMC802A* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS 🖵

View a parametric search of comparable parts.

EVALUATION KITS

• HMC802A Evaluation Board

DOCUMENTATION

Data Sheet

 HMC802ALP3E: 20 dB GaAs MMIC 1-Bit Digital Postive Control Attenuator, DC to 10 GHz Data Sheet

DESIGN RESOURCES

- HMC802A Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- · Symbols and Footprints

DISCUSSIONS

View all HMC802A EngineerZone Discussions.

SAMPLE AND BUY 🖵

Visit the product page to see pricing options.

TECHNICAL SUPPORT 🖳

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK 🖳

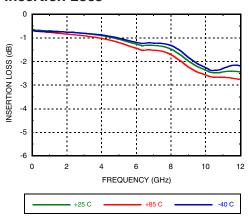
Submit feedback for this data sheet.



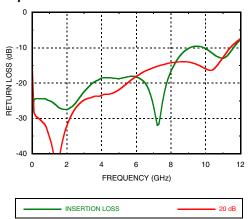
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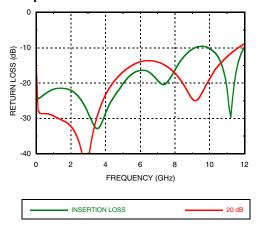
Insertion Loss



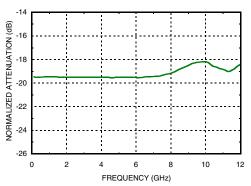
Input Return Loss



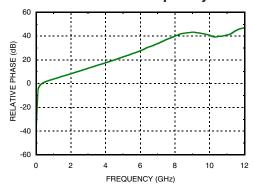
Output Return Loss



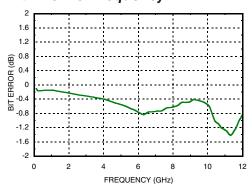
Relative Attenuation



Relative Phase vs. Frequency



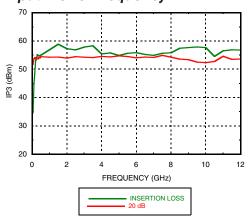
Bit Error vs. Frequency



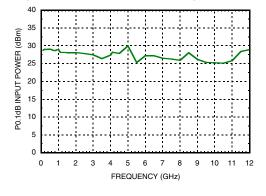


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Input IP3 vs. Frequency

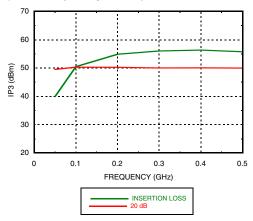


Input Power for 1 dB Compression



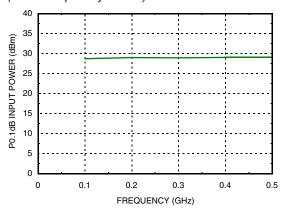
Input IP3 vs. Frequency

(Low Frequency Detail)



Input Power for 0.1 dB Compression

(Low Frequency Detail)



Truth Table

| Control Voltage Input | Attenuation State |
|-----------------------|--------------------------|
| V1 | RF1 - RF2 |
| High | Reference Insertion Loss |
| Low | 20 dB |

Bias Voltage & Current

| $Vdd = +5 Vdc \pm 10\%$ | | | |
|-------------------------|--------------------|--|--|
| Vdd (Vdc) | ldd (Typ.) (mA) | | |
| 4.5 | 0.32 | | |
| 5.0 | 0.33 | | |
| 5.5 | 0.34 | | |

Control Voltage

| State | Bias Condition | |
|-----------------|-------------------------|--|
| Low | 0 to +0.8V @ -1 μA Typ. | |
| High | +2 to +5V @ 30 μA Typ. | |
| Note: Vdd = +5V | | |



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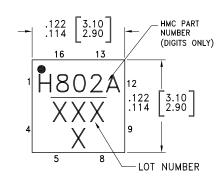
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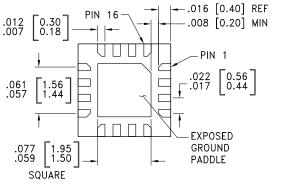
Absolute Maximum Ratings

| RF Input Power (DC - 10 GHz) | +29.3 dBm |
|---|----------------|
| Control Voltage Range (V1) | -1 to Vdd + 1V |
| Bias Voltage (Vdd) | +7 Vdc |
| Channel Temperature | 150 °C |
| Continuous Pdiss (T = 85 °C) (derate 12 mW/°C above 85 °C) | 0.84 W |
| Thermal Resistance (channel to ground paddle) | 77.4 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |
| ESD Sensitivity (HBM) | Class 1A |

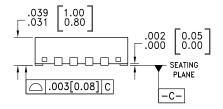


Outline Drawing





BOTTOM VIEW



NOTES

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
 PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

| | Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking [2] |
|---|-------------|--|---------------|---------------------|----------------------|
| H | HMC802ALP3E | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL3 ^[1] | <u>H802A</u> XXXX |

^[1] Max peak reflow temperature of 260 °C

^{[2] 4-}Digit lot number XXXX



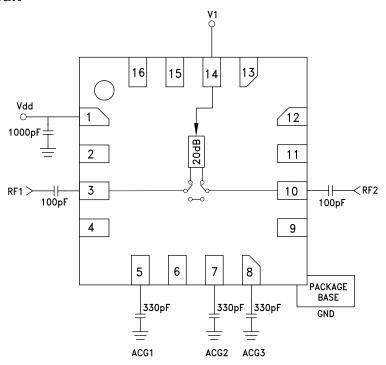
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Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|----------------------|------------------|--|---------------------|
| 1 | Vdd | Supply Voltage. | |
| 2, 4, 9, 11 | GND | These pins and the exposed ground paddle must be connected to RF/DC ground. | GND = |
| 3, 10 | RF1, RF2 | These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required. Select value based on lowest frequency of operation. | RF1 RF2 |
| 5, 7, 8 | ACG1, ACG2, ACG3 | External capacitor to ground is required. Select value for lowest frequency of operation. Place capacitor as close to pins as possible. | |
| 6, 12, 13, 15, 16 | N/C | The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally. | |
| 14 | V1 | See truth table and control voltage table. | V1 0 180K 500 = |

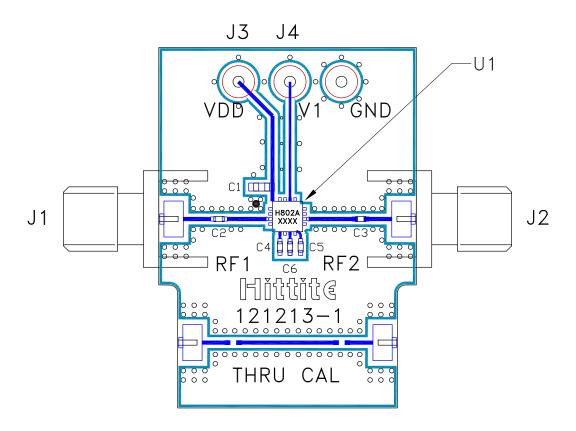
Application Circuit





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Evaluation PCB



List of Materials for Evaluation PCB EV1HMC802ALP3 [1]

| Item | Description |
|---------|--------------------------------|
| J1, J2 | PCB Mount SMA Connector |
| J3, J4 | DC Connector |
| C1 | 1000 pF Capacitor, 0603 Pkg. |
| C2, C3 | 100 pF Capacitor, 0402 Pkg. |
| C4 - C6 | 330 pF Capacitor, 0402 Pkg. |
| U1 | HMC802ALP3E Digital Attenuator |
| PCB [2] | 121213 Evaluation PCB |

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Analog Devices Inc. upon request.

^[2] Circuit Board Material: Rogers 4350